

SURFACE MOUNT SILICON BI-DIRECTIONAL TRANSIENT VOLTAGE SUPPRESSOR



# Central Semiconductor Corp.

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# **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CFTVS3V3B is a low leakage, fast response, bi-directional TVS in the space saving SOD-882 surface mount package. This device is designed to protect sensitive equipment connected to high speed data lines against ESD damage.

### MARKING CODE: 3

#### APPLICATIONS:

- Data line protection
- User interface protection
- Charging/power port protection

# FEATURES:

- Space saving SOD-882 package
- · Low leakage current

MAXIMUM RATINGS: (T <sub>A</sub> =25°C)	SYMBOL		UNITS
Peak Power Dissipation (8x20µs)	<sup>Р</sup> РК	40	W
Electrical Fast Transient (IEC 61000-4-4) (5x50ns)	EFT	40	А
ESD Voltage (IEC 61000-4-2, Air)	V <sub>ESD</sub>	30	kV
ESD Voltage (IEC 61000-4-2, Contact)	V <sub>ESD</sub>	30	kV
Operating Junction Temperature	ТЈ	-55 to +125	°C
Storage Temperature	T <sub>stg</sub>	-55 to +150	°C

#### ELECTRICAL CHARACTERISTICS: (T<sub>A</sub>=25°C)

Maximum Reverse Stand-off Voltage V <sub>RWM</sub>	Minimum Breakdown Voltage V <sub>BR</sub> @ <sup>I</sup> T	Test Current I <sub>T</sub>	Maximum Reverse Leakage Current I <sub>R</sub> @ V <sub>RWM</sub>	Clarr Volt (8x2	mum nping tage 0µs) D Ipp	TLP CI	,	Typical Dynamic Resistance (Note 1) R <sub>DYN</sub>	Maximum Junction Capacitance @ 0V Bias CJ
v	v	μΑ	μΑ	v	А	v	А	Ω	pF
3.3	3.5	2.0	0.5	6.5	1.0	6.0	4.0	0.25	10
3.3	3.5	2.0	0.5	8.0	5.0	7.0	8.0	0.25	10

Note 1: Transmission Line Pulse (TLP) conditions:  $Z_0=50\Omega$ , tp=100ns

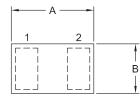
R8 (28-July 2015)



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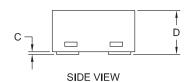
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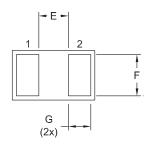
## SOD-882 CASE - MECHANICAL OUTLINE



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TOP VIEW





BOTTOM VIEW R2

DIMENSIONS				
	INCHES		MILLIMETERS	
SYMBOL	MIN	MAX	MIN	MAX
А	0.037	0.042	0.95	1.05
В	0.022	0.026	0.55	0.65
С	0.000	0.002	0.00	0.05
D	0.017	0.022	0.45	0.55
E	0.014		0.36	
F	0.017	0.022	0.45	0.55
G	0.008	0.013	0.22	0.32
SOD-882 (REV:R2)				

**PIN CONFIGURATION** 



LEAD CODE: 1) Anode 1 2) Anode 2

MARKING CODE: 3

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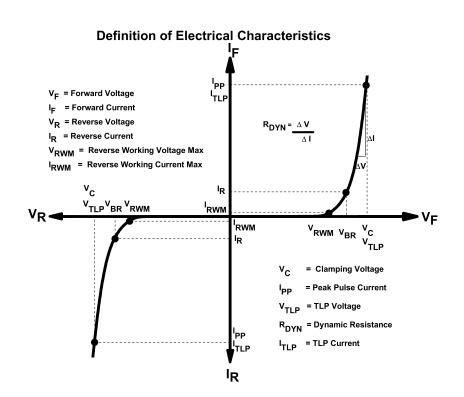
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**BI-DIRECTIONAL** TRANSIENT VOLTAGE SUPPRESSOR

#### **Reverse Voltage** Leakage Current 5.4 100 I<sub>R</sub>, Reverse Current (nA) V<sub>BR</sub>, Breakdown Voltage (Volts) 5.3 10 5.2 I<sub>R</sub>=1 mA 5.1 <del>|-</del> -25 0.1 <del>|\_</del> 25 V<sub>R</sub>=3.3V 25 75 ò 50 75 100 125 50 100 T<sub>A</sub>, Ambient Temperature (°C) T<sub>A</sub>, Ambient Temperature (°C) Peak Clamping Voltage (V<sub>C</sub>) vs Peak Pulse Current (I<sub>PP</sub>) Capacitance 10 6.0 -V<sub>C</sub>, Clamping Voltage (Volts) C, Capacitance (pF) 8 5.5 -7 6 -5 -5.0 -4 3 4.5 2 -T<sub>A</sub>=25°C \_\_\_\_\_ f=1.0MHz -1 -0+ 4.0 -3

### **TYPICAL ELECTRICAL CHARACTERISTICS**

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IPP, Peak Pulse Current (Amps)

125

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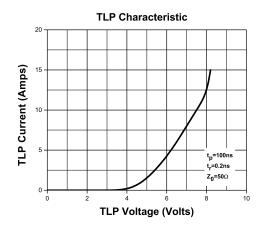
V<sub>R</sub>, Reverse Voltage (Volts)



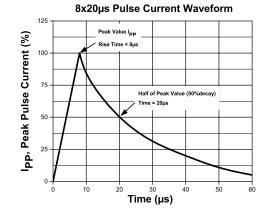
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### TYPICAL ELECTRICAL CHARACTERISTICS



#### Ipp Current Derating in Percentage (%) **Power & Current Derating** 125 Р<sub>РК</sub>, PeakPower Derating or 100 75 50 · 25 0+ 25 50 75 100 125 150 T<sub>A</sub>, Ambient Temperature (°C)

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# OUTSTANDING SUPPORT AND SUPERIOR SERVICES

#### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options

#### DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- · Environmental regulation compliance
- Customer specific screening
- · Up-screening capabilities

· Custom product packing

Custom bar coding for shipments

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- · Custom product and package development

#### REQUESTING PRODUCT PLATING

- If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when 1. ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

#### CONTACT US

#### **Corporate Headquarters & Customer Support Team**

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